

PDF DATA SHEET

EFORCEAUSTRALIA PTY.LTD ACN:159 503 401

MDL-III-1550R/1~200mW

SPECIFICATIONS

INFRARED DIODE LASER At 1550nm

Diode infrared laser module at 1550 nm, is made features of ultra compact, long lifetime, low cost and easy operating, which is used in measurement, communication, spectrum analysis, etc.



Wavelength (nm)	1550+10			
Output power (mW)	>1, 10, 50, 100,, 200			
Energy distribution	Even			
Beam Spot	Round			
Power stability (rms, over 4 hours)	<1%, <3%, <5%			
Warm-up time (minutes)	<5			
Beam divergence, full angle (mrad)	<8.0			
Dimensions of beam at the aperture (mm)	~2.0			
Beam height from base plate (mm)	24.8			
Operating temperature (°C)	10~35			
Power supply (90-264VAC or 5VDC)	PSU-III-LED	PSU-III-FDA	PSU-III-OEM	
Modulation option	TTL/Analog 1Hz-5KHz, 1Hz-10KHz, 1Hz-30KHz, and TTL on/off			
Expected lifetime (hours)	10000			
Warranty	1 year			





MxL-III-1550R	PSU-III-LED	PSU-III-FDA	PSU-III-OEM
139(L)×73(W) ×46. 2(H) mm ³ , 0.6kg	153 (L) ×155(W) ×92 (H) mm ³ , 1.5kg	DPSSL DRIVER	100 (L) ×62(W) ×56 (H) mm ³ , 0.2kg
	155		